## NSN 5962-01-364-1274

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
5 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
7.0 volts power source  Memory Device Type:
Memory Device Type:
Memory Device Type: Rom
Memory Device Type: Rom Terminal Type And Quantity:
Memory Device Type: Rom Terminal Type And Quantity: 14 printed circuit
Memory Device Type: Rom Terminal Type And Quantity: 14 printed circuit Shelf Life:
Memory Device Type: Rom Terminal Type And Quantity: 14 printed circuit Shelf Life: N/a
Memory Device Type: Rom Terminal Type And Quantity: 14 printed circuit Shelf Life: N/a
Memory Device Type:  Rom  Terminal Type And Quantity:  14 printed circuit  Shelf Life:  N/a  Unit Of Measure:
Memory Device Type:  Rom  Terminal Type And Quantity:  14 printed circuit  Shelf Life:  N/a  Unit Of Measure:   Demilitarization:
Memory Device Type:  Rom  Terminal Type And Quantity:  14 printed circuit  Shelf Life:  N/a  Unit Of Measure:   Demilitarization:  Yes - demil/mli
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